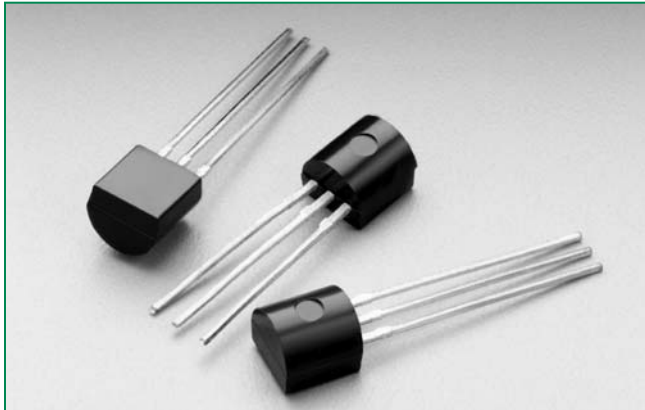


**RoHS TCR22-x Series**

**Description**

Excellent unidirectional switches for phase control applications such as heating and motor speed controls. Sensitive gate SCRs are easily triggered with microAmps of current as furnished by sense coils, proximity switches, and microprocessors.

**Features & Benefits**

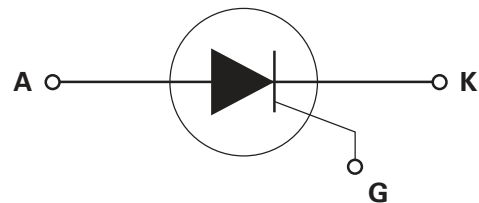
- RoHS compliant
- Glass – passivated junctions
- Voltage capability up to 600 V
- Surge capability up to 20 A

**Main Features**

Symbol	Value	Unit
$I_{T(RMS)}$	1.5	A
$V_{DRM}/V_{RRM}$	400 to 600	V
$I_{GT}$	200	$\mu A$

**Applications**

Typical applications are capacitive discharge systems for strobe lights and gas engine ignition. Also controls for power tools, home/brown goods and white goods appliances.

**Schematic Symbol**

**Absolute Maximum Ratings – Sensitive SCRs**

Symbol	Parameter	Test Conditions	Value	Unit
$I_{T(RMS)}$	RMS on-state current	$T_C = 40^\circ C$	1.5	A
$I_{TSM}$	Peak non-repetitive surge current	single half cycle; $f = 50\text{Hz}$ ; $T_J(\text{initial}) = 25^\circ C$	16	A
		single half cycle; $f = 60\text{Hz}$ ; $T_J(\text{initial}) = 25^\circ C$	20	
$I^2t$	$I^2t$ Value for fusing	$t_p = 8.3 \text{ ms}$	1.6	$A^2s$
$di/dt$	Critical rate of rise of on-state current	$f = 60 \text{ Hz}$ ; $T_J = 110^\circ C$	50	$A/\mu s$
$I_{GM}$	Peak gate current	$T_J = 110^\circ C$	1	A
$P_{G(AV)}$	Average gate power dissipation	$T_J = 110^\circ C$	0.1	W
$T_{stg}$	Storage temperature range		-40 to 150	$^\circ C$
$T_J$	Operating junction temperature range		-40 to 110	$^\circ C$

**Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)**

Symbol	Test Conditions		Value	Unit	
$I_{GT}$	$V_D = 6\text{V}; R_L = 100\ \Omega$		MAX.	200	$\mu\text{A}$
$V_{GT}$			MAX.	0.8	V
dv/dt	$V_D = V_{DRM}; R_{GK} = 1\text{k}\Omega$	400V	MIN.	40	V/ $\mu\text{s}$
		600V		30	
$V_{GD}$	$V_D = V_{DRM}; R_L = 3.3\ \text{k}\Omega; T_J = 110^\circ\text{C}$		MIN.	0.25	V
$V_{GRM}$	$I_{GR} = 10\ \mu\text{A}$		MIN.	6	V
$I_H$	$I_T = 200\text{mA}$ (initial)		MAX.	5	mA
$t_q$	(1)		MAX.	50	$\mu\text{s}$
$t_{gt}$	$I_G = 2 \times I_{GT}; \text{PW} = 15\ \mu\text{s}; I_T = 3\text{A}$		TYP.	3.5	$\mu\text{s}$

(1)  $I_T = 1\text{A}; t_p = 50\ \mu\text{s}; \text{dv/dt} = 5\text{V}/\mu\text{s}; \text{di/dt} = 10\text{A}/\mu\text{s}$

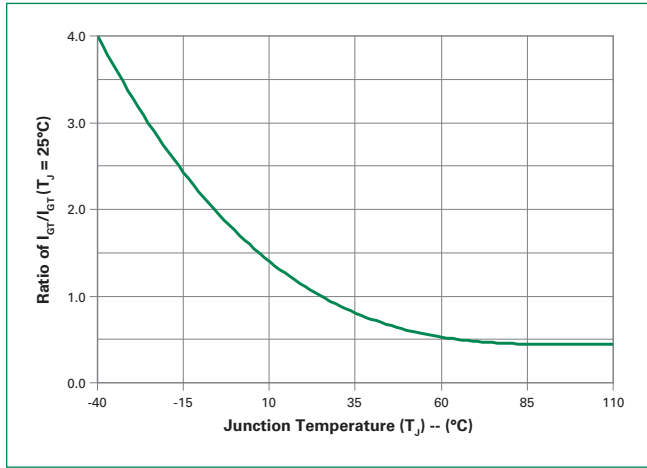
**Static Characteristics**

Symbol	Test Conditions		Value	Unit	
$V_{TM}$	$I_T = 3\text{A}; t_p = 380\ \mu\text{s}$		MAX.	1.5	V
$I_{DRM} / I_{RRM}$	$V_{DRM} = V_{RRM}$	$T_J = 25^\circ\text{C}$	MAX.	1	$\mu\text{A}$
		400V		2	
		600V		100	
		$T_J = 110^\circ\text{C}$			

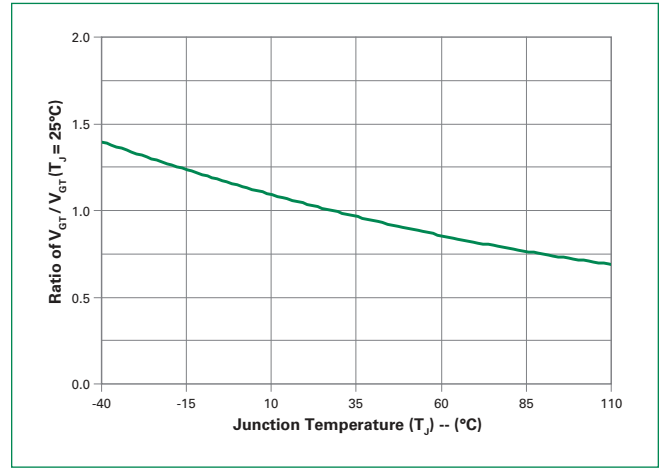
**Thermal Resistances**

Symbol	Parameter	Value	Unit
$R_{\theta(J-C)}$	Junction to case (AC)	50	$^\circ\text{C}/\text{W}$
$R_{\theta(J-A)}$	Junction to ambient	160	$^\circ\text{C}/\text{W}$

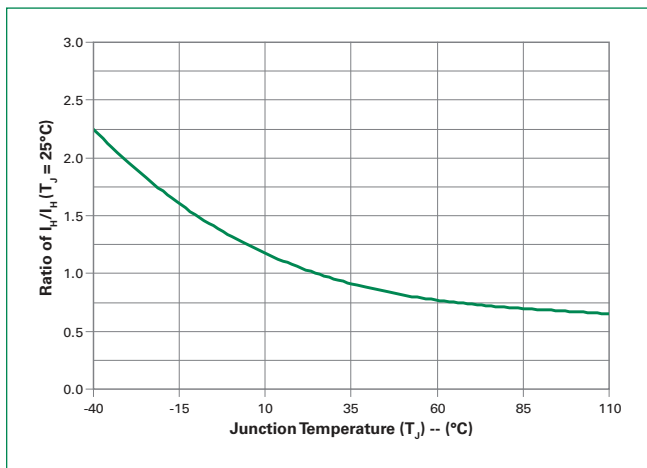
**Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature**



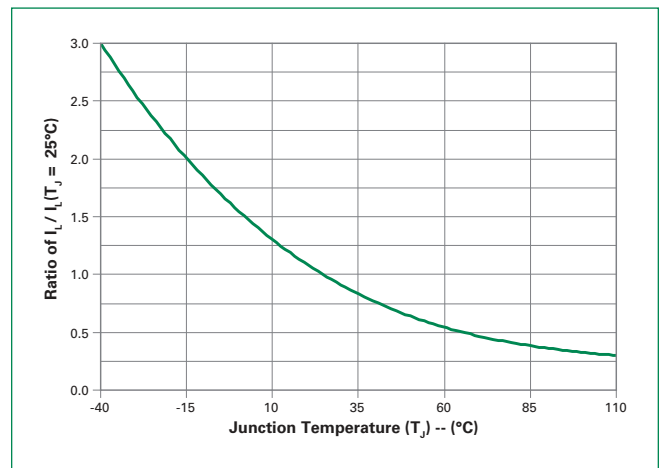
**Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature**



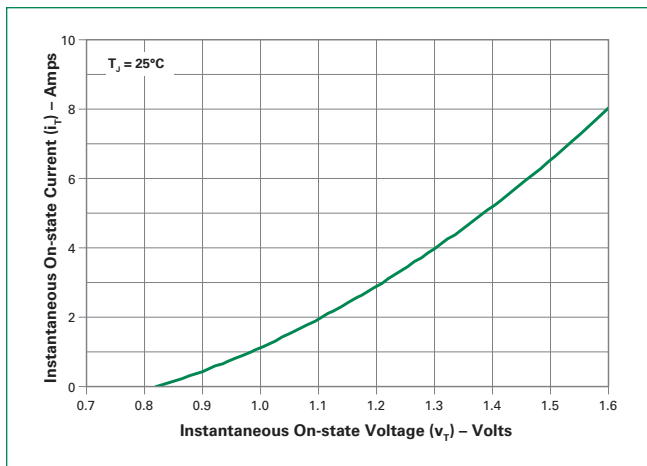
**Figure 3: Normalized DC Holding Current vs. Junction Temperature**



**Figure 4: Normalized DC Latching Current vs. Junction Temperature**



**Figure 5: On-State Current vs. On-State Voltage (Typical)**



**Figure 6: Power Dissipation (Typical) vs. RMS On-State Current**

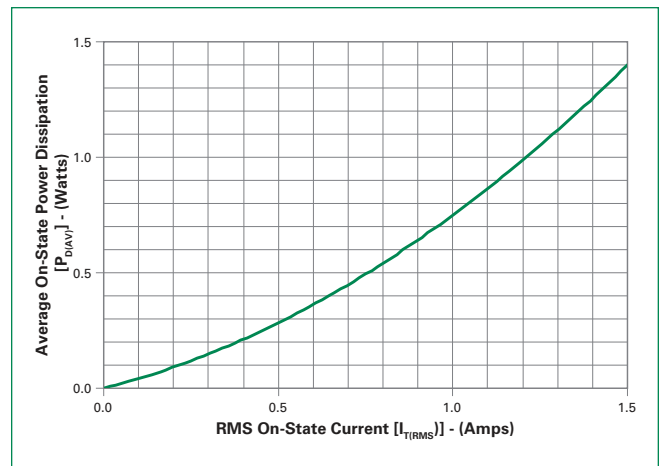


Figure 7: Maximum Allowable Case Temperature vs. RMS On-State Current

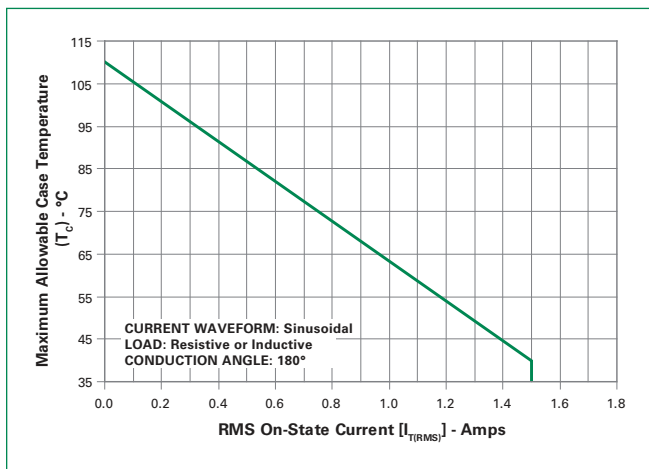


Figure 8: Maximum Allowable Case Temperature vs. Average On-State Current

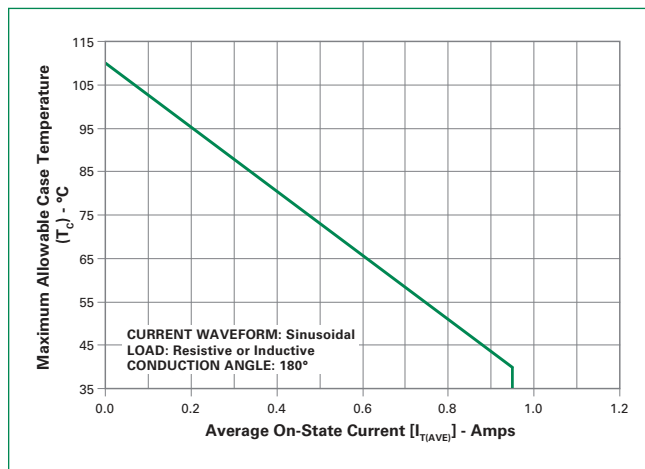


Figure 9: Maximum Allowable Ambient Temperature vs. RMS On-State Current

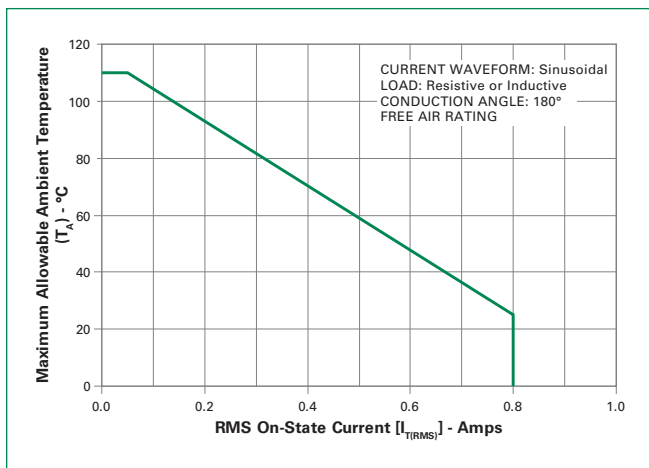


Figure 10: Maximum Allowable Ambient Temperature vs. Average On-State Current

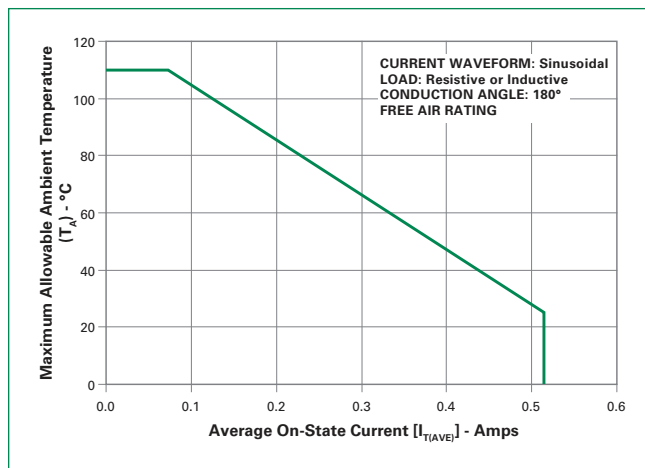


Figure 11: Peak Repetitive Capacitor Discharge Current

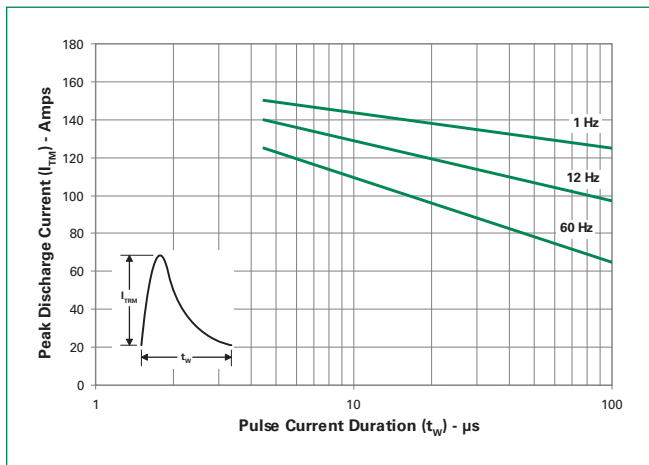
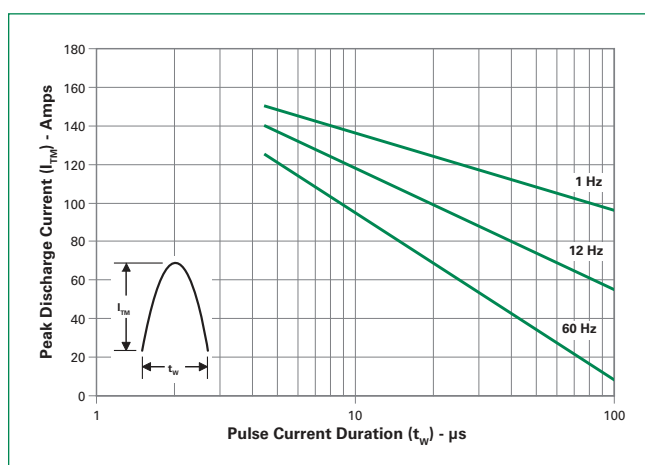
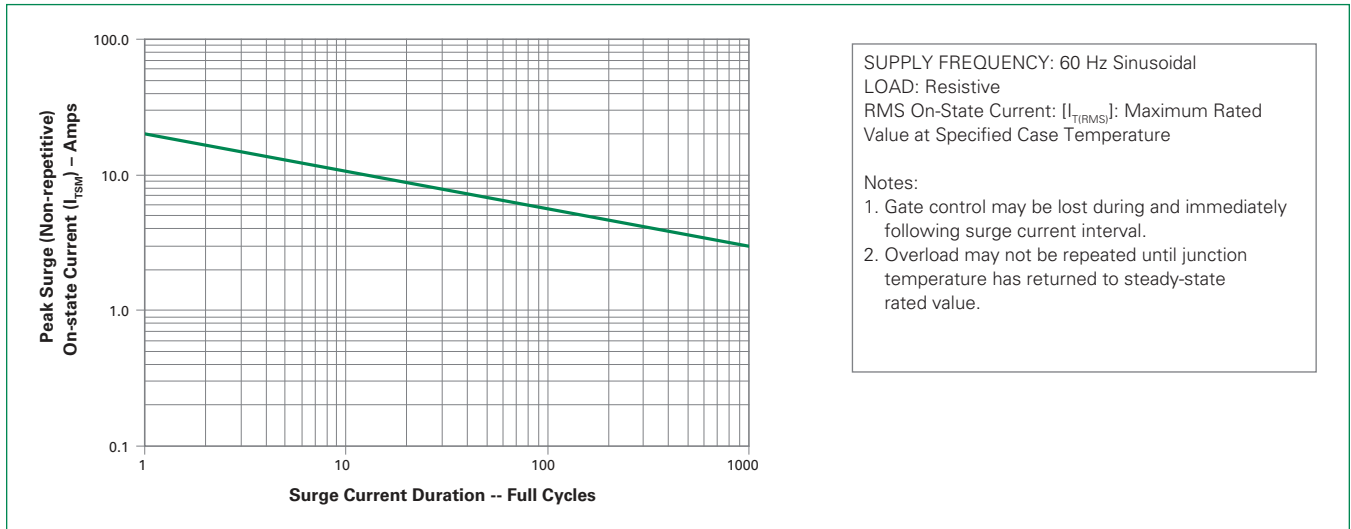


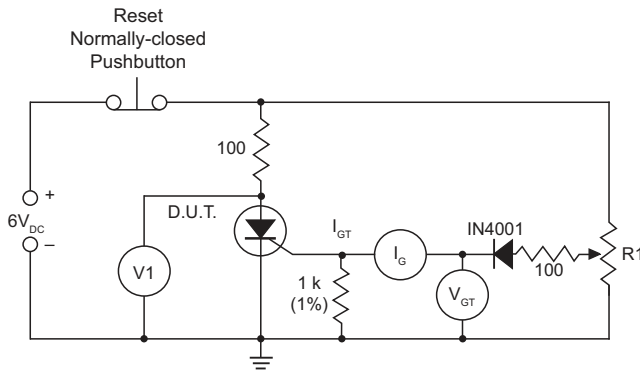
Figure 12: Peak Repetitive Sinusoidal Pulse Current



**Figure 13: Surge Peak On-State Current vs. Number of Cycles**



**Figure 14: Simple Test Circuit for Gate Trigger Voltage and Current**



Note: V1 — 0 V to 10 V dc meter  
V<sub>GT</sub> — 0 V to 1 V dc meter  
I<sub>G</sub> — 0 mA to 1 mA dc milliammeter  
R1 — 1 k potentiometer

To measure gate trigger voltage and current, raise gate voltage (V<sub>GT</sub>) until meter reading V1 drops from 6 V to 1 V. Gate trigger voltage is the reading on V<sub>GT</sub> just prior to V1 dropping. Gate trigger current I<sub>GT</sub> can be computed from the relationship

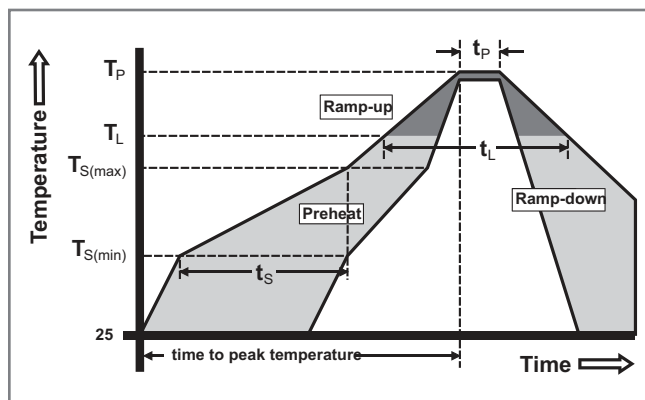
$$I_{GT} = I_G - \frac{V_{GT}}{1000} \text{ Amps}$$

where I<sub>G</sub> is reading (in amperes) on meter just prior to V1 dropping

Note: I<sub>GT</sub> may turn out to be a negative quantity (trigger current flows out from gate lead). If negative current occurs, I<sub>GT</sub> value is not a valid reading. Remove 1 k resistor and use I<sub>G</sub> as the more correct I<sub>GT</sub> value. This will occur on 12 μA gate products.

### Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ( $T_{s(min)}$ )	150°C
	- Temperature Max ( $T_{s(max)}$ )	200°C
	- Time (min to max) ( $t_s$ )	60 – 190 secs
Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)		5°C/second max
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		5°C/second max
Reflow	- Temperature ( $T_L$ ) (Liquidus)	217°C
	- Temperature ( $t_L$ )	60 – 150 seconds
Peak Temperature ( $T_p$ )		260 <sup>+0/-5</sup> °C
Time within 5°C of actual peak Temperature ( $t_p$ )		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature ( $T_p$ )		8 minutes Max.
Do not exceed		280°C



### Physical Specifications

<b>Terminal Finish</b>	100% Matt Tin-plated/Pb-free Solder Dipped
<b>Body Material</b>	UL recognized epoxy meeting flammability classification 94V-0
<b>Lead Material</b>	Copper Alloy

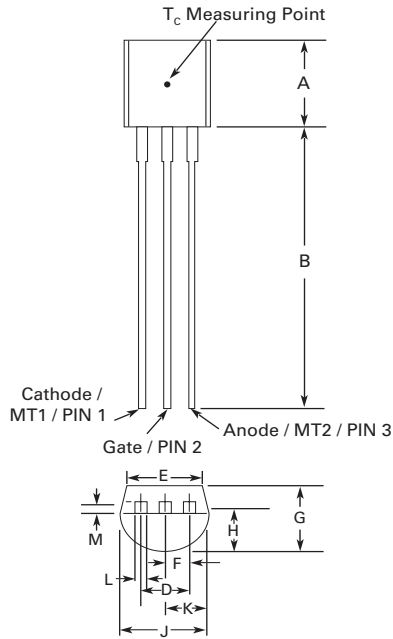
### Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

### Environmental Specifications

Test	Specifications and Conditions
<b>AC Blocking</b>	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 110°C for 1008 hours
<b>Temperature Cycling</b>	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
<b>Temperature/Humidity</b>	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
<b>High Temp Storage</b>	MIL-STD-750, M-1031, 1008 hours; 150°C
<b>Low-Temp Storage</b>	1008 hours; -40°C
<b>Thermal Shock</b>	MIL-STD-750, M-1056 10 cycles; 0°C to 100°C; 5-min dwell-time at each temperature; 10 sec (max) transfer time between temperature
<b>Autoclave</b>	EIA / JEDEC, JESD22-A102 168 hours (121°C at 2 ATMs) and 100% R/H
<b>Resistance to Solder Heat</b>	MIL-STD-750 Method 2031
<b>Solderability</b>	ANSI/J-STD-002, category 3, Test A
<b>Lead Bend</b>	MIL-STD-750, M-2036 Cond E

**Dimensions – TO-92 (E Package)**



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.176	0.196	4.47	4.98
B	0.500		12.70	
D	0.095	0.105	2.41	2.67
E	0.150		3.81	
F	0.046	0.054	1.16	1.37
G	0.135	0.145	3.43	3.68
H	0.088	0.096	2.23	2.44
J	0.176	0.186	4.47	4.73
K	0.088	0.096	2.23	2.44
L	0.013	0.019	0.33	0.48
M	0.013	0.017	0.33	0.43

All leads insulated from case. Case is electrically nonconductive.

**Product Selector**

Part Number	Voltage				Gate Sensitivity	Type	Package
	400V	600V	800V	1000V			
TCR22-6	X				200µA	Sensitive SCR	TO-92
TCR22-8		X			200µA	Sensitive SCR	TO-92

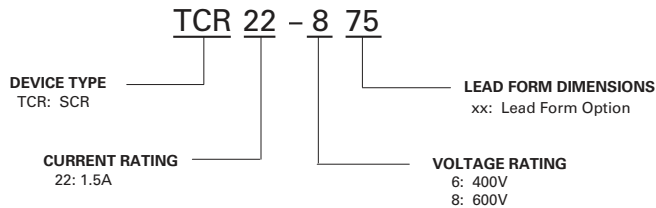
Note: x = Voltage

**Packing Options**

Part Number	Marking	Weight	Packing Mode	Base Quantity
TCR22-x	TCR22-x	0.19 g	Bulk	2000
TCR22-xRP	TCR22-x	0.19 g	Reel Pack	2000
TCR22-xAP	TCR22-x	0.19 g	Ammo Pack	2000

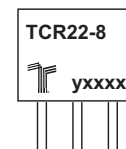
Note: x = Voltage

**Part Numbering System**



**Part Marking System**

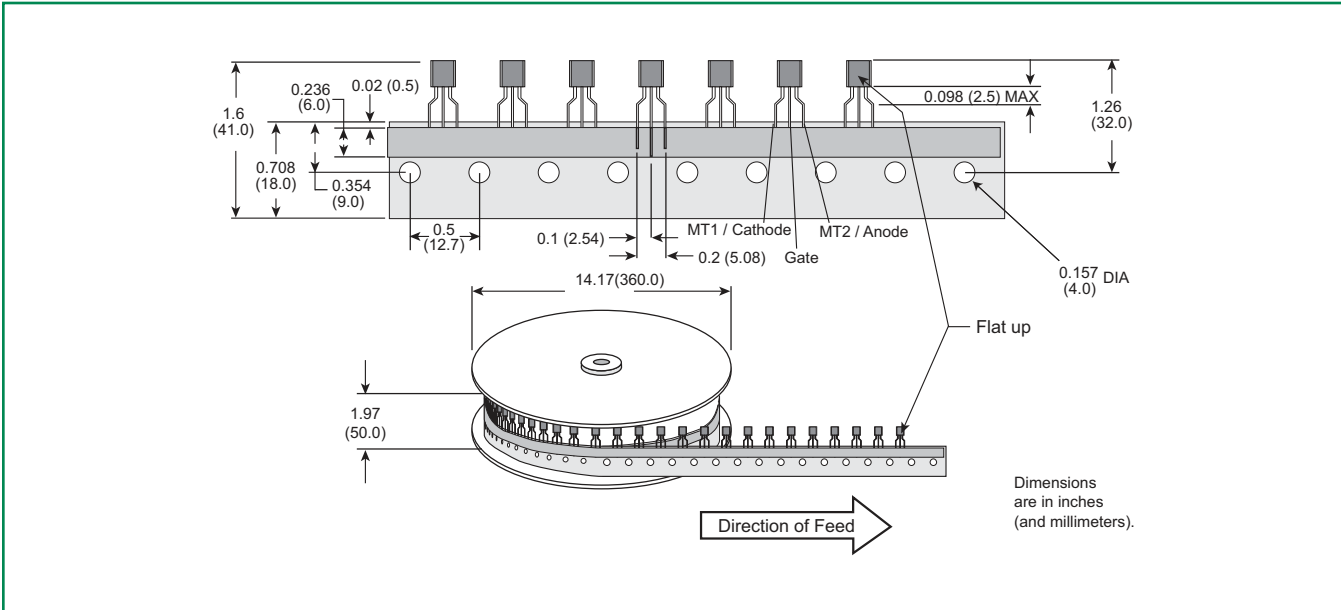
**TO-92 (E Package)**



1.5A SCRs

**TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications**

Meets all EIA-468-B 1994 Standards



**TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications**

Meets all EIA-468-B 1994 Standards

